## NSN 5961-01-464-8911

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-8911 **Inclosure Material:** Glass **Overall Length:** 37.720 millimeters **Terminal Length:** 4.700 millimeters **End Application:** Aircraft, airlifter c-17a **Mounting Facility Quantity: Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 125.0 breakdown voltage, dc and 10.4 breakdown voltage, dc **Current Rating Per Characteristic:** 15.60 nanoamperes source cutoff current minor **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 150.0 degrees celsius case **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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